### **Features**

- Low-voltage and Standard-voltage Operation
  - $-2.7 (V_{CC} = 2.7 V \text{ to } 5.5 V)$
  - $-1.8 (V_{CC} = 1.8V \text{ to } 3.6V)$
- Internally Organized 16,384 x 8 and 32,768 x 8
- **Two-wire Serial Interface**
- Schmitt Trigger, Filtered Inputs for Noise Suppression
- Bidirectional Data Transfer Protocol
- 1 MHz (5V), 400 kHz (2.7V, 2.5V) and 100 kHz (1.8V) Compatibility
- Write Protect Pin for Hardware and Software Data Protection
- 64-byte Page Write Mode (Partial Page Writes Allowed)
- Self-timed Write Cycle (5 ms Max)
- High Reliability
  - Endurance: One Million Write Cycles
  - Data Retention: 40 Years
- Extended Temperature and Lead-free/Halogen-free **Devices Available**
- 8-lead JEDEC PDIP, 8-lead JEDEC and EIAJ SOIC, 8-lead MAP, 8-lead TSSOP, 8-lead SAP and 8-ball dBGA2 Packages
- Die Sales: Wafer Form, Waffle Pack, and Bumped Wafers

### Description

The AT24C128/256 provides 131,072/262,144 bits of serial electrically erasable and programmable read only memory (EEPROM) organized as 16,384/32,768 words of 8 bits each. The device's cascadable feature allows up to 4 devices to share a common Two-wire bus. The device is optimized for use in many industrial and commercial applications where low power and low voltage operation are essential. The devices are available in space-saving 8-lead JEDEC PDIP, 8-lead JEDEC SOIC, 8-lead EIAJ SOIC, 8-lead MAP (24C128), 8-lead TSSOP, 8-lead SOIC Array Package and 8-ball dBGA2 packages. In addition, the entire family is available in 2.7V (2.7V to 5.5V) and 1.8V (1.8V to 3.6V) versions.

GND

Table 1. Pin Configuration			
Pin Name	Function		
A0 - A1	Address Inputs		
SDA	Serial Data		
SCL	Serial Clock Input		
WP	Write Protect		
NC	No Connect		
GND	Ground		

8	lead	I PDI	Ρ
Г		)	
A0 □ A1 □	1	8	
A1 🗆	2	7	🗅 WF

			$\cup$	
8	□vcc	A0 🗆	1 8	þ vcc
7	WP	A1 🗆	2 7	D WP
6	SCL	NC 🗆	36	
5		GND 🗆	4 5	
-				
ead SOIC	2	8-	lead MAF	)
	-			
0				A0
-				
-		SCL 6	3	NC
		SDA 5	] [4]	GND
5		L		
	-	Bo	ottom Viev	v
dBGA2		8	A2 heal	<b>)</b>
		0		_
① A0		VCC 8	] [1	AO
2 A1		WP Z	2	A1
3 NC	;	SCL 6	3	NC
4 GN	ID	SDA 5	4	GND
				1
m view		Bo	ottom View	N
	7 6 5 ead SOIC 8 8 7 6 5 dBGA2 (1) A0 (2) A1 (3) NC	7 WP 6 SCL 5 SDA ead SOIC 8 VCC 7 WP 6 SCL 5 SDA dBGA2 (1) A0 (2) A1 (3) NC (4) GND	A1 A0 VCC B A1 WP Z A1 BC A1 BC A1 BC A1 BC A1 BC A1 BC A0 VCC B A1 BC A1 C BC A1	0       VCC       A1       2       7         7       WP       A1       2       7         6       SCL       NC       3       6         5       SDA       GND       4       5         add SOIC       8-lead MAF         8       VCC       WP       7       22         7       WP       SCL       6       33         6       SCL       SDA       5       4         5       SDA       SDA       5       4         6       SCL       SDA       5       4         6       SCL       SDA       5       4         6       SCL       SDA       5       4         0       A0       VCC       8       1         1       A0       VCC       8       1       2         3       NC       SCL       6       3       3         4       GND       SDA       5       4

8-lead TSSOP



# Two-wire Serial **EEPROMs**

128K (16,384 x 8)

256K (32,768 x 8)

# AT24C128 AT24C256<sup>(1)</sup>

Note: 1. Not recommended for new design; please refer to AT24C256B datasheet.





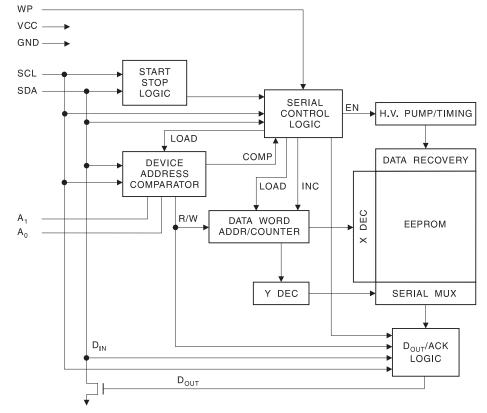


### **Absolute Maximum Ratings\***

Operating Temperature	–55°C to +125°C
Storage Temperature	–65°C to +150°C
Voltage on Any Pin with Respect to Ground	1.0V to +7.0V
Maximum Operating Voltage	6.25V
DC Output Current	5.0 mA

#### Figure 1. Block Diagram

\*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



# **Pin Description** SERIAL CLOCK (SCL): The SCL input is used to positive edge clock data into each EEPROM device and negative edge clock data out of each device.

**SERIAL DATA (SDA):** The SDA pin is bidirectional for serial data transfer. This pin is opendrain driven and may be wire-ORed with any number of other open-drain or open collector devices.

**DEVICE/ADDRESSES (A1, A0):** The A1 and A0 pins are device address inputs that are hardwired or left not connected for hardware compatibility with other AT24CXX devices. When the pins are hardwired, as many as four 128K/256K devices may be addressed on a single bus system (device addressing is discussed in detail under the Device Addressing section). If the pins are left floating, the A1 and A0 pins will be internally pulled down to GND if the capacitive coupling to the circuit board V<sub>CC</sub> plane is <3 pF. If coupling is >3 pF, Atmel recommends connecting the address pins to GND.

**WRITE PROTECT (WP):** The write protect input, when connected to GND, allows normal write operations. When WP is connected high to  $V_{CC}$ , all write operations to the memory are inhibited. If the pin is left floating, the WP pin will be internally pulled down to GND if the capacitive coupling to the circuit board  $V_{CC}$  plane is <3 pF. If coupling is >3 pF, Atmel recommends connecting the pin to GND.

Memory<br/>OrganizationAT24C128/256, 128K/256K SERIAL EEPROM: The 128K/256K is internally organized as<br/>256/512 pages of 64-bytes each. Random word addressing requires a 14/15-bit data word<br/>address.





#### Table 2. Pin Capacitance<sup>(1)</sup>

Applicable over recommended operating range from  $T_A = 25^{\circ}C$ , f = 1.0 MHz,  $V_{CC} = +1.8V$ .

Symbol	Test Condition	Мах	Units	Conditions
C <sub>I/O</sub>	Input/Output Capacitance (SDA)	8	pF	$V_{I/O} = 0V$
C <sub>IN</sub>	Input Capacitance (A <sub>0</sub> , A <sub>1</sub> , SCL)	6	pF	$V_{IN} = 0V$

Note: 1. This parameter is characterized and is not 100% tested.

#### Table 3. DC Characteristics<sup>(1)</sup>

Applicable over recommended operating range from:  $T_{AI} = -40^{\circ}C$  to  $+85^{\circ}C$ ,  $V_{CC} = +1.8V$  to +5.5V;  $T_{AE} = -40^{\circ}C$  to  $+125^{\circ}C^{(2)}$ ,  $V_{CC} = +2.7V$  to +5.5V(unless otherwise noted).

Symbol	Parameter	Test Condition		Min	Тур	Max	Units
V <sub>CC1</sub>	Supply Voltage			1.8		3.6	V
V <sub>CC2</sub>	Supply Voltage			2.5		5.5	V
V <sub>CC3</sub>	Supply Voltage			4.5		5.5	V
I <sub>CC1</sub>	Supply Current	$V_{\rm CC} = 5.0 V$	READ at 400 kHz		1.0	2.0	mA
I <sub>CC2</sub>	Supply Current	$V_{\rm CC} = 5.0 V$	WRITE at 400 kHz		2.0	3.0	mA
	Standby Current	$V_{\rm CC} = 1.8V$				0.2	μA
I <sub>SB1</sub>	(1.8V option)	$V_{\rm CC} = 3.6 V$	$V_{IN} = V_{CC} \text{ or } V_{SS}$			2.0	
	Standby Current	$V_{\rm CC} = 2.5 V$	$V_{IN} = V_{CC} \text{ or } V_{SS}$			0.5	μA
I <sub>SB2</sub>	(2.5V option)	$V_{\rm CC} = 5.5 V$				6.0	
I <sub>SB3</sub>	Standby Current (5.0V option)	V <sub>CC</sub> = 4.5 - 5.5V	$V_{IN} = V_{CC} \text{ or } V_{SS}$			6.0	μA
ILI	Input Leakage Current	$V_{IN} = V_{CC} \text{ or } V_{SS}$			0.10	3.0	μA
I <sub>LO</sub>	Output Leakage Current	$V_{OUT} = V_{CC} \text{ or } V_{SS}$			0.05	3.0	μA
V <sub>IL</sub>	Input Low Level <sup>(1)</sup>			-0.6		V <sub>CC</sub> x 0.3	V
V <sub>IH</sub>	Input High Level <sup>(1)</sup>			V <sub>CC</sub> x 0.7		V <sub>CC</sub> + 0.5	V
V <sub>OL2</sub>	Output Low Level	$V_{\rm CC} = 3.0 V$	I <sub>OL</sub> = 2.1 mA			0.4	V
V <sub>OL1</sub>	Output Low Level	V <sub>CC</sub> = 1.8V	I <sub>OL</sub> = 0.15 mA			0.2	V

Notes: 1.  $V_{IL}$  min and  $V_{IH}$  max are reference only and are not tested.

2. The AT24C128/256 bearing the process letter "B" on the package (the mark is located in the lower right corner on the topside of the package) are approved for operation in the extended temperature range.

4

#### Table 4. AC Characteristics - Industrial Temperatures

Applicable over recommended operating range from  $T_{AI} = -40^{\circ}C$  to  $+85^{\circ}C$ ,  $V_{CC} = +1.8V$  to +5.5V, CL = 100 pF (unless otherwise noted). Test conditions are listed in Note 2.

Symbol		1.8-volt		2	.5-volt	5.0-volt		
	Parameter	Min	Max	Min	Max	Min	Max	Units
f <sub>SCL</sub>	Clock Frequency, SCL		100		400		1000	kHz
t <sub>LOW</sub>	Clock Pulse Width Low	4.7		1.3		0.4		μs
t <sub>HIGH</sub>	Clock Pulse Width High	4.0		0.6		0.4		μs
t <sub>AA</sub>	Clock Low to Data Out Valid	0.1	4.5	0.05	0.9	0.05	0.55	μs
t <sub>BUF</sub>	Time the bus must be free before a new transmission can start <sup>(1)</sup>	4.7		1.3		0.5		μs
t <sub>HD.STA</sub>	Start Hold Time	4.0		0.6		0.25		μs
t <sub>SU.STA</sub>	Start Set-up Time	4.7		0.6		0.25		μs
t <sub>HD.DAT</sub>	Data In Hold Time	0		0		0		μs
t <sub>SU.DAT</sub>	Data In Set-up Time	200		100		100		ns
t <sub>R</sub>	Inputs Rise Time <sup>(1)</sup>		1.0		0.3		0.3	μs
t <sub>F</sub>	Inputs Fall Time <sup>(1)</sup>		300		300		100	ns
t <sub>SU.STO</sub>	Stop Set-up Time	4.7		0.6		0.25		μs
t <sub>DH</sub>	Data Out Hold Time	100		50		50		ns
t <sub>wR</sub>	Write Cycle Time		20 or 5 <sup>(3)</sup>		10 or 5 <sup>(3)</sup>		10 or 5 <sup>(3)</sup>	ms
Endurance <sup>(1)</sup>	25°C, Page Mode		<u>.</u>	100k or	1,000,000 <sup>(4)</sup>		<u>.</u>	Write Cycles

Notes: 1. This parameter is characterized and is not 100% tested.

2. AC measurement conditions:

 $\rm R_L$  (connects to V\_{CC}): 1.3 k\Omega (2.5V, 5V), 10 k $\Omega$  (1.8V)

Input pulse voltages: 0.3  $V_{CC}$  to 0.7  $V_{CC}$ 

Input rise and fall times:  $\leq$  50 ns

Input and output timing reference voltages: 0.5  $\mathrm{V}_{\mathrm{CC}}$ 

- 3. The Write Cycle Time of 5 ms only applies to the AT24C128/256 devices bearing the process letter "B" on the package (the mark is located in the lower right corner on the top side of the package).
- 4. The AT24C128/256 bearing the process letter "B" in the package (the mark is located in the lower right corner on the top side of the package), guarantees 1 million write cycle endurance (1.8 3.6V).



# <u>AIMEL</u>

#### Table 5. AC Characteristics<sup>(5)</sup> – Extended Temperatures

Applicable over recommended operating range from  $T_{AE} = -40^{\circ}C$  to  $+125^{\circ}C$ ,  $V_{CC} = +2.7V$  to +5.5V, CL = 100 pF (unless otherwise noted). Test conditions are listed in Note 2.

		2	2.7-volt		5.0-volt	
Symbol	Parameter	Min	Мах	Min	Мах	Units
f <sub>SCL</sub>	Clock Frequency, SCL		400		1000	kHz
t <sub>LOW</sub>	Clock Pulse Width Low	1.3		0.4		μs
t <sub>HIGH</sub>	Clock Pulse Width High	0.6		0.4		μs
t <sub>AA</sub>	Clock Low to Data Out Valid	0.05	0.9	0.05	0.55	μs
t <sub>BUF</sub>	Time the bus must be free before a new transmission can start <sup>(1)</sup>	1.3		0.5		μs
t <sub>HD.STA</sub>	Start Hold Time	0.6		0.25		μs
t <sub>SU.STA</sub>	Start Set-up Time	0.6		0.25		μs
t <sub>HD.DAT</sub>	Data In Hold Time	0		0		μs
t <sub>SU.DAT</sub>	Data In Set-up Time	100		100		ns
t <sub>R</sub>	Inputs Rise Time <sup>(1)</sup>		0.3		0.3	μs
t <sub>F</sub>	Inputs Fall Time <sup>(1)</sup>		300		100	ns
t <sub>SU.STO</sub>	Stop Set-up Time	0.6		0.25		μs
t <sub>DH</sub>	Data Out Hold Time	50		50		ns
t <sub>wR</sub>	Write Cycle Time		10 or 5 <sup>(3)</sup>		10 or 5 <sup>(3)</sup>	ms
Endurance <sup>(1)</sup>	25°C, Page Mode		100k or 1	100k or 1,000,000 <sup>(4)</sup>		Write Cycles

Notes: 1. This parameter is characterized and is not 100% tested.

AC measurement conditions:

 $\rm R_L$  (connects to V\_{CC}): 1.3 k\Omega (2.5V, 5V), 10 k $\Omega$  (1.8V)

Input pulse voltages: 0.3  $V_{CC}$  to 0.7  $V_{CC}$ 

Input rise and fall times:  $\leq$  50 ns

Input and output timing reference voltages: 0.5  $V_{\text{CC}}$ 

- 3. The Write Cycle Time of 5 ms only applies to the AT24C128/256 devices bearing the process letter "B" on the package (the mark is located in the lower right corner on the top side of the package).
- 4. The AT24C128/256 bearing the process letter "B" in the package (the mark is located in the lower right corner on the top side of the package), guarantees 1 million write cycle endurance (1.8 3.6V).
- 5. The AT24C128/256 bearing the process letter "B" on the package (the mark is located in the lower right corner on the topside of the package) are approved for operation in the extended temperature range.

### Device Operation

**CLOCK and DATA TRANSITIONS:** The SDA pin is normally pulled high with an external device. Data on the SDA pin may change only during SCL low time periods (see Figure 4 on page 8). Data changes during SCL high periods will indicate a start or stop condition as defined below.

**START CONDITION:** A high-to-low transition of SDA with SCL high is a start condition which must precede any other command (see Figure 5 on page 9).

**STOP CONDITION:** A low-to-high transition of SDA with SCL high is a stop condition. After a read sequence, the stop command will place the EEPROM in a standby power mode (see Figure 5 on page 9).

**ACKNOWLEDGE:** All addresses and data words are serially transmitted to and from the EEPROM in 8-bit words. The EEPROM sends a zero during the ninth clock cycle to acknowledge that it has received each word.

**STANDBY MODE:** The AT24C128/256 features a low power standby mode which is enabled: a) upon power-up and b) after the receipt of the STOP bit and the completion of any internal operations.

**MEMORY RESET:** After an interruption in protocol, power loss or system reset, any two-wire part can be reset by following these steps: (a) Clock up to 9 cycles, (b) look for SDA high in each cycle while SCL is high and then (c) create a start condition as SDA is high.





Figure 2. Bus Timing (SCL: Serial Clock, SDA: Serial Data I/O®)

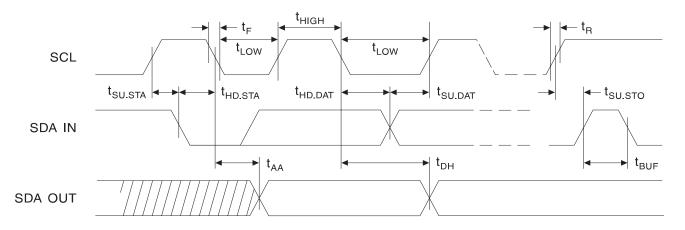
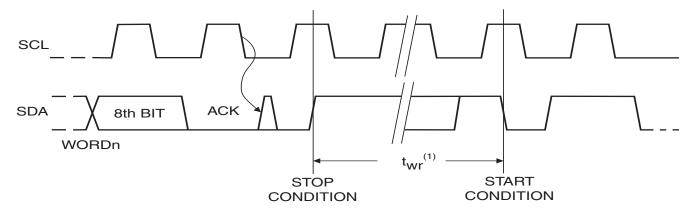
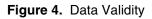
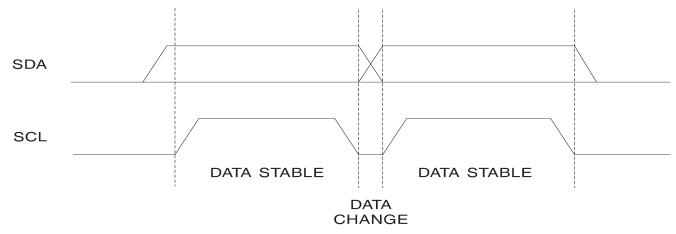


Figure 3. Write Cycle Timing (SCL: Serial Clock, SDA: Serial Data I/O)

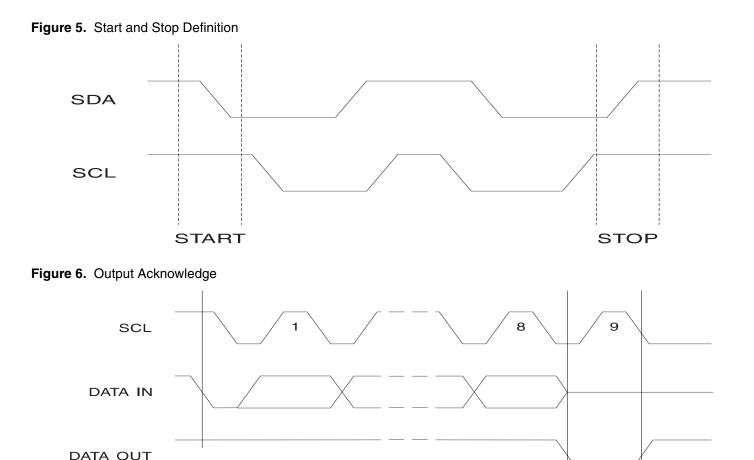


Note: 1. The write cycle time  $t_{WR}$  is the time from a valid stop condition of a write sequence to the end of the internal clear/write cycle.





# 8 AT24C128/256



Device

START

Addressing

The 128K/256K EEPROM requires an 8-bit device address word following a start condition to enable the chip for a read or write operation (see Figure 7 on page 11). The device address word consists of a mandatory one, zero sequence for the first five most significant bits as shown. This is common to all two-wire EEPROM devices.

ACKNOWLEDGE

The 128K/256K uses the two device address bits A1, A0 to allow as many as four devices on the same bus. These bits must compare to their corresponding hardwired input pins. The A1 and A0 pins use an internal proprietary circuit that biases them to a logic low condition if the pins are allowed to float.

The eighth bit of the device address is the read/write operation select bit. A read operation is initiated if this bit is high and a write operation is initiated if this bit is low.

Upon a compare of the device address, the EEPROM will output a zero. If a compare is not made, the device will return to a standby state.

**DATA SECURITY:** The AT24C128/256 has a hardware data protection scheme that allows the user to write protect the whole memory when the WP pin is at  $V_{CC}$ .



0670S-SEEPR-5/06



### Write Operations

**BYTE WRITE:** A write operation requires two 8-bit data word addresses following the device address word and acknowledgment. Upon receipt of this address, the EEPROM will again respond with a zero and then clock in the first 8-bit data word. Following receipt of the 8-bit data word, the EEPROM will output a zero. The addressing device, such as a microcontroller, then must terminate the write sequence with a stop condition. At this time the EEPROM enters an internally-timed write cycle,  $t_{WR}$ , to the nonvolatile memory. All inputs are disabled during this write cycle and the EEPROM will not respond until the write is complete (see Figure 8 on page 11).

PAGE WRITE: The 128K/256K EEPROM is capable of 64-byte page writes.

A page write is initiated the same way as a byte write, but the microcontroller does not send a stop condition after the first data word is clocked in. Instead, after the EEPROM acknowledges receipt of the first data word, the microcontroller can transmit up to 63 more data words. The EEPROM will respond with a zero after each data word received. The microcontroller must terminate the page write sequence with a stop condition (see Figure 9 on page 12).

The data word address lower 6 bits are internally incremented following the receipt of each data word. The higher data word address bits are not incremented, retaining the memory page row location. When the word address, internally generated, reaches the page boundary, the following byte is placed at the beginning of the same page. If more than 64 data words are transmitted to the EEPROM, the data word address will "roll over" and previous data will be overwritten. The address "roll over" during write is from the last byte of the current page to the first byte of the same page.

**ACKNOWLEDGE POLLING:** Once the internally-timed write cycle has started and the EEPROM inputs are disabled, acknowledge polling can be initiated. This involves sending a start condition followed by the device address word. The read/write bit is representative of the operation desired. Only if the internal write cycle has completed will the EEPROM respond with a zero, allowing the read or write sequence to continue.

### Read Operations

Read operations are initiated the same way as write operations with the exception that the read/write select bit in the device address word is set to one. There are three read operations: current address read, random address read and sequential read.

**CURRENT ADDRESS READ:** The internal data word address counter maintains the last address accessed during the last read or write operation, incremented by one. This address stays valid between operations as long as the chip power is maintained. The address "roll over" during read is from the last byte of the last memory page, to the first byte of the first page.

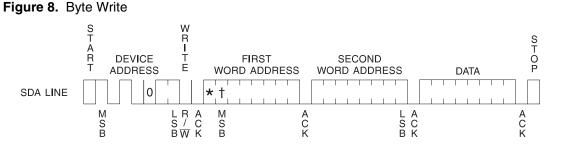
Once the device address with the read/write select bit set to one is clocked in and acknowledged by the EEPROM, the current address data word is serially clocked out. The microcontroller does not respond with an input zero but does generate a following stop condition (see Figure 10 on page 12).

**RANDOM READ:** A random read requires a "dummy" byte write sequence to load in the data word address. Once the device address word and data word address are clocked in and acknowledged by the EEPROM, the microcontroller must generate another start condition. The microcontroller now initiates a current address read by sending a device address with the read/write select bit high. The EEPROM acknowledges the device address and serially clocks out the data word. The microcontroller does not respond with a zero but does generate a following stop condition (see Figure 11 on page 12).

**SEQUENTIAL READ:** Sequential reads are initiated by either a current address read or a random address read. After the microcontroller receives a data word, it responds with an acknowledge. As long as the EEPROM receives an acknowledge, it will continue to increment the data word address and serially clock out sequential data words. When the memory address limit is reached, the data word address will "roll over" and the sequential read will continue. The sequential read operation is terminated when the microcontroller does not respond with a zero but does generate a following stop condition (see Figure 12 on page 12).

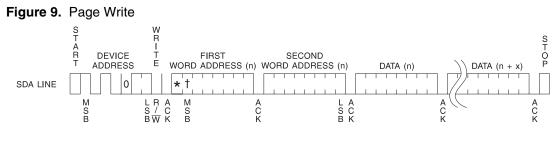
Figure 7. Device Address











Notes: (\* = DON'T CARE bit) († = DON'T CARE bit for the 128K)

Figure 10. Current Address Read

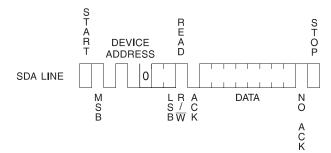
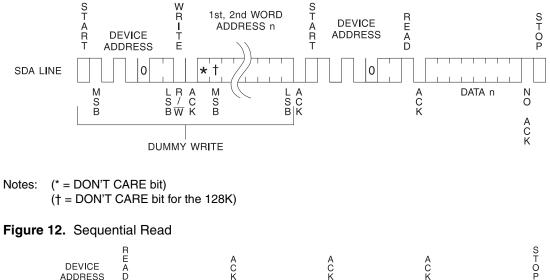
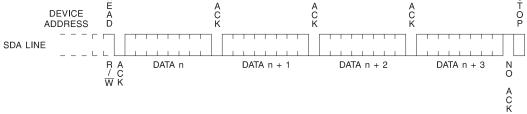


Figure 11. Random Read





<sup>12</sup> **AT24C128/256** 

# AT24C128 Ordering Information<sup>(1)</sup>

Ordering Code	Package	Operation Range
AT24C128-10PI-2.7	8P3	
AT24C128N-10SI-2.7	8S1	Industrial Temperature
AT24C128W-10SI-2.7	8S2	(–40°C to 85°C)
AT24C128-10TI-2.7	8A2	
AT24C128-10PI-1.8	8P3	
AT24C128N-10SI-1.8	8S1	Industrial Temperature
AT24C128W-10SI-1.8	8S2	(–40°C to 85°C)
AT24C128-10TI-1.8	8A2	
AT24C128-10PU-2.7 <sup>(2)</sup>	8P3	
AT24C128-10PU-1.8 <sup>(2)</sup>	8P3	
AT24C128N-10SU-2.7 <sup>(2)</sup>	8S1	
AT24C128N-10SU-1.8 <sup>(2)</sup>	8S1	
AT24C128W-10SU-2.7 <sup>(2)</sup>	8S2	Lead-free/Halogen-free/
AT24C128W-10SU-1.8 <sup>(2)</sup>	8S2	Industrial Temperature
AT24C128-10TU-2.7 <sup>(2)</sup>	8A2	(–40°C to 85°C)
AT24C128-10TU-1.8 <sup>(2)</sup>	8A2	
AT24C128U2-10UU-1.8 <sup>(2)</sup>	8U2-1	
AT24C128Y1-10YU-1.8 <sup>(2)</sup>	8Y1	
AT24C128Y4-10YU-1.8 <sup>(2)</sup>	8Y4	
AT24C128-W2.7-11 <sup>(3)</sup>	Die Sale	Industrial Temperature
AT24C128-W1.8-11 <sup>(3)</sup>	Die Sale	(-40°C to 85°C)

Notes: 1. For 2.7V devices used in the 4.5V to 5.5V range, please refer to performance values in the AC and DC characteristics tables.

2. "U" designates Green package + RoHS compliant.

3. Available in waffle pack and wafer form; order as SL719 for wafer form. Bumped die available upon request. Please contact Serial EEPROM Marketing.

	Package Type	
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)	
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline Package (JEDEC SOIC)	
8S2	8-lead, 0.200" Wide, Plastic Gull Wing Small Outline Package (EIAJ SOIC)	
8U2-1	8-ball, die Ball Grid Array Package (dBGA2)	
8Y1	8-lead, 4.90 mm x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP)	
8Y4	8-lead, 6.00 mm x 4.90 mm Body, Dual Footprint, Non-leaded, Small Array Package (SAP)	
8A2	8-lead, 4.4 mm Body, Plastic Thin Shrink Small Outline Package (TSSOP)	
	Options	
-2.7	Low-voltage (2.7V to 5.5V)	
-1.8	Low-voltage (1.8V to 3.6V)	





### AT24C256 Ordering Information<sup>(1)</sup>

Ordering Code	Package	Operation Range
AT24C256-10PI-2.7	8P3	
AT24C256N-10SI-2.7	8S1	Industrial Temperature
AT24C256W-10SI-2.7	8S2	(−40°C to 85°C)
AT24C256-10TI-2.7	8A2	
AT24C256-10PI-1.8	8P3	
AT24C256N-10SI-1.8	8S1	Industrial Temperature
AT24C256W-10SI-1.8	8S2	(–40°C to 85°C)
AT24C256-10TI-1.8	8A2	
AT24C256-10PU-2.7 <sup>(2)</sup>	8P3	
AT24C256-10PU-1.8 <sup>(2)</sup>	8P3	
AT24C256N-10SU-2.7 <sup>(2)</sup>	8S1	
AT24C256N-10SU-1.8 <sup>(2)</sup>	8S1	
AT24C256W-10SU-2.7 <sup>(2)</sup>	8S2	Lead-free/Halogen-free/
AT24C256W-10SU-1.8 <sup>(2)</sup>	8S2	Industrial Temperature
AT24C256-10TU-2.7 <sup>(2)</sup>	8A2	(–40°C to 85°C)
AT24C256-10TU-1.8 <sup>(2)</sup>	8A2	
AT24C256U2-10UU-1.8 <sup>(2)</sup>	8U2-1	
AT24C256Y1-10YU-1.8 <sup>(2)</sup>	8Y1	
AT24C256Y4-10YU-1.8 <sup>(2)</sup>	8Y4	
AT24C256-W2.7-11 <sup>(3)</sup>	Die Sale	Industrial Temperature
AT24C256-W1.8-11 <sup>(3)</sup>	Die Sale	(−40°C to 85°C)

Notes: 1. This device is not recommended for new design. Please refer to AT24C256B datasheet. For 2.7V devices used in the 4.5V to 5.5V range, please refer to performance values in the AC and DC characteristics tables.

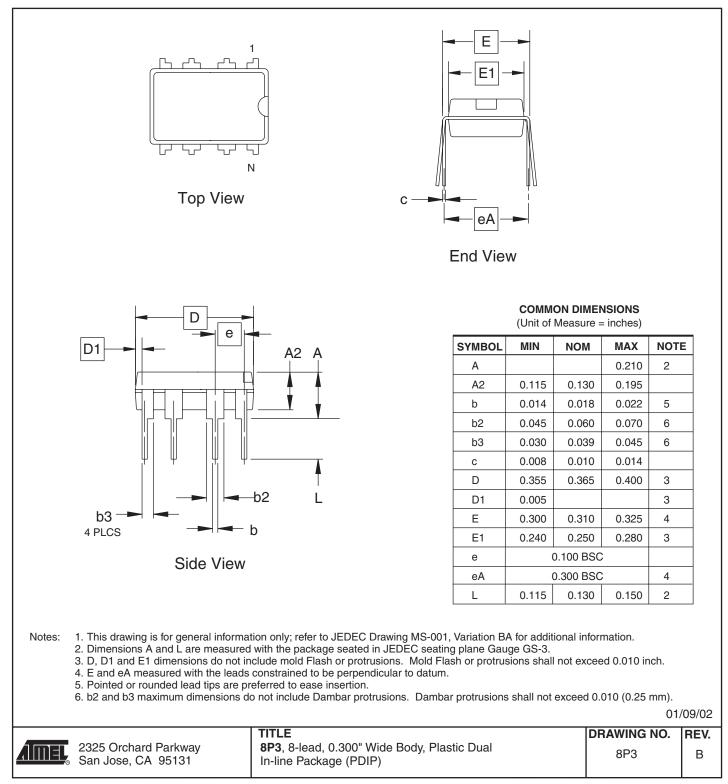
2. "U" designates Green Package + RoHS compliant.

3. Available in waffle pack and wafer form; order as SL719 for wafer form. Bumped die available upon request. Please contact Serial EEPROM Marketing.

Package Type	
8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)	
8-lead, 0.150" Wide, Plastic Gull Wing Small Outline Package (JEDEC SOIC)	
8-lead, 0.200" Wide, Plastic Gull Wing Small Outline Package (EIAJ SOIC)	
8-ball, die Ball Grid Array Package (dBGA2)	
8-lead, 4.90 mm x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP)	
8-lead, 6.00 mm x 4.90 mm Body, Dual Footprint, Non-leaded, Small Array Package (SAP)	
8-lead, 4.4 mm Body, Plastic Thin Shrink Small Outline Package (TSSOP)	
Options	
Low-voltage (2.7V to 5.5V)	
Low-voltage (1.8V to 3.6V)	
	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)         8-lead, 0.150" Wide, Plastic Gull Wing Small Outline Package (JEDEC SOIC)         8-lead, 0.200" Wide, Plastic Gull Wing Small Outline Package (EIAJ SOIC)         8-lead, 0.200" Wide, Plastic Gull Wing Small Outline Package (EIAJ SOIC)         8-lead, 0.200" Wide, Plastic Gull Wing Small Outline Package (EIAJ SOIC)         8-lead, 0.200" Wide, Plastic Gull Wing Small Outline Package (EIAJ SOIC)         8-lead, 4.90 mm x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP)         8-lead, 6.00 mm x 4.90 mm Body, Dual Footprint, Non-leaded, Small Array Package (SAP)         8-lead, 4.4 mm Body, Plastic Thin Shrink Small Outline Package (TSSOP)         Options         Low-voltage (2.7V to 5.5V)

### **Packaging Information**

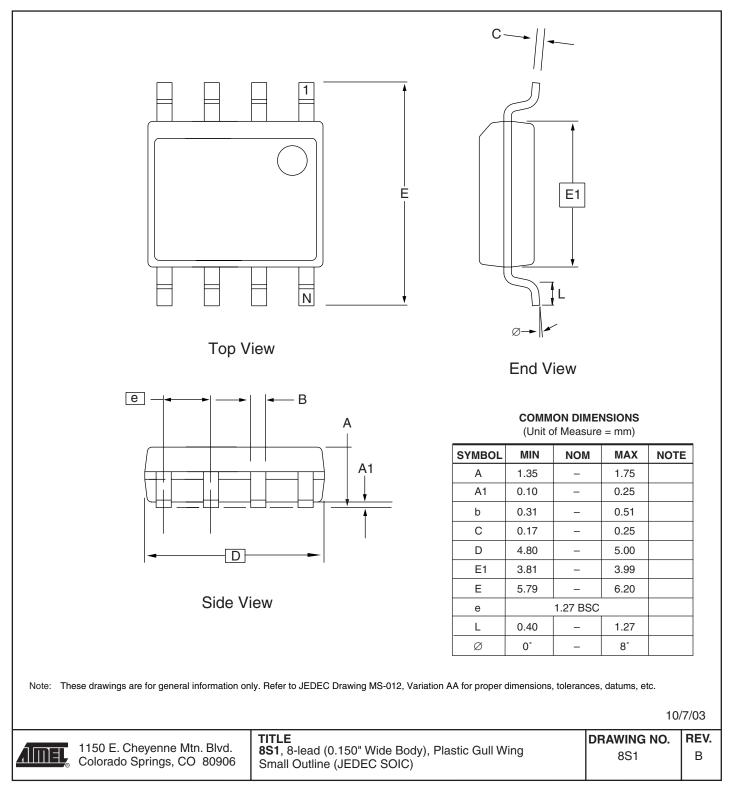
### 8P3 – PDIP







#### 8S1 – JEDEC SOIC

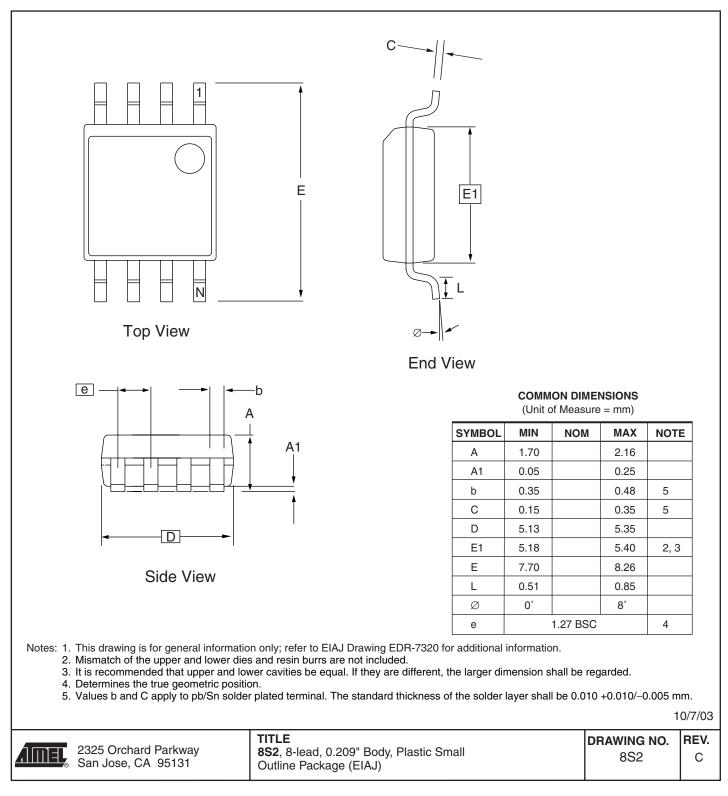


Downloaded from Elcodis.com electronic components distributor

16

AT24C128/256

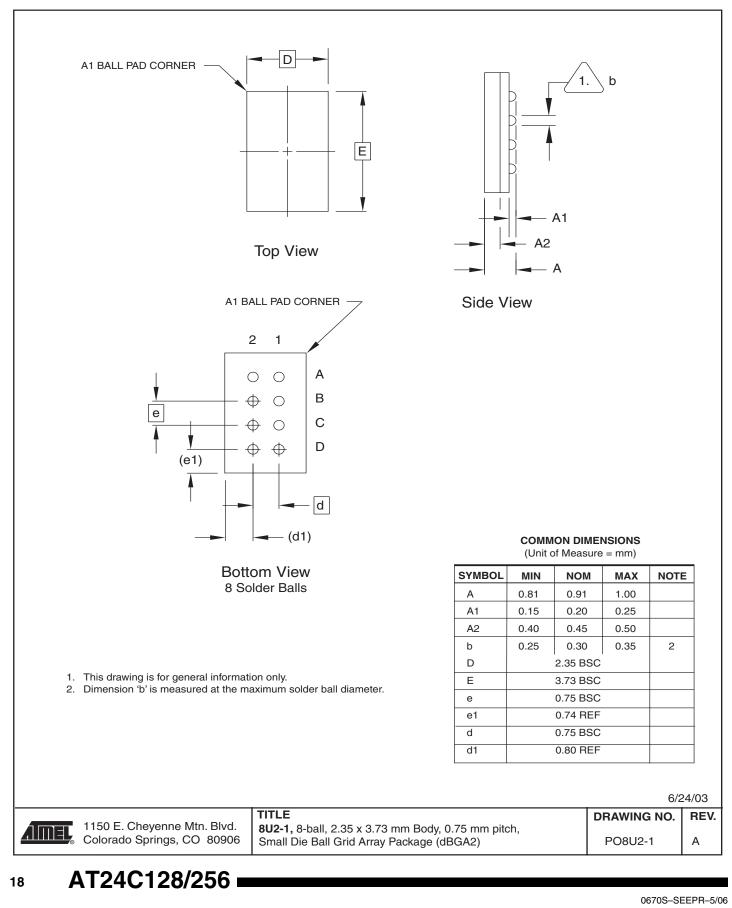
#### 8S2 - EIAJ SOIC

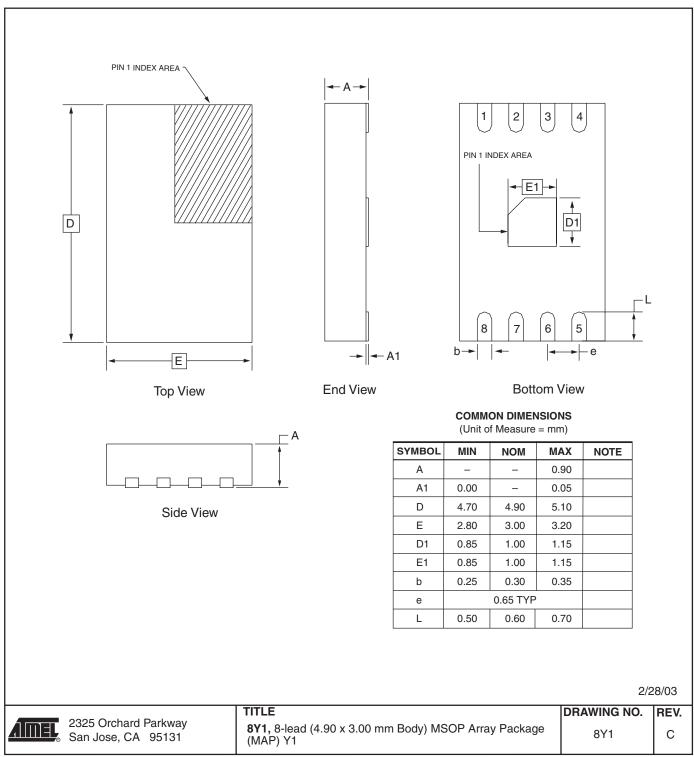






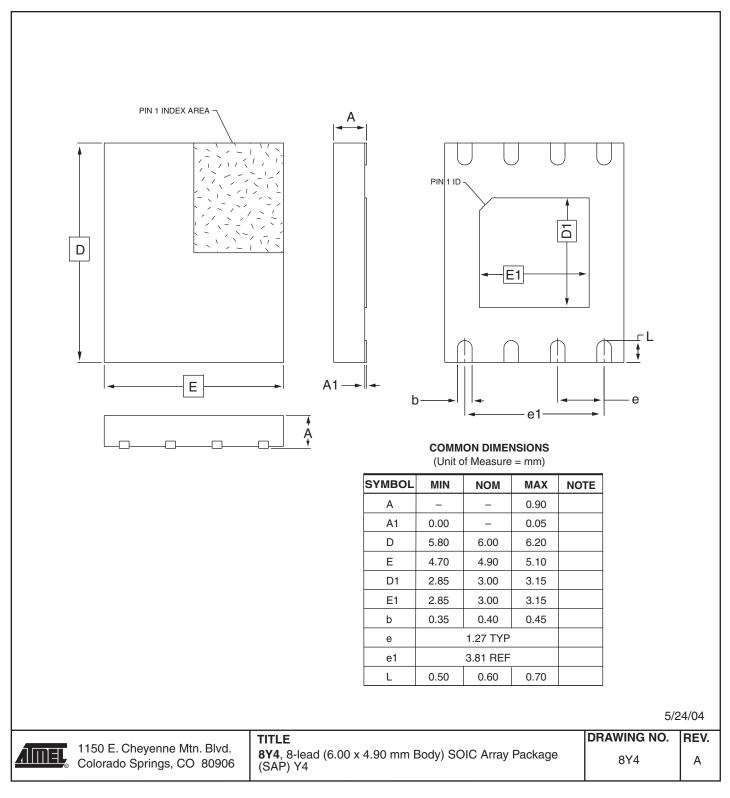
#### 8U2-1 - dBGA2





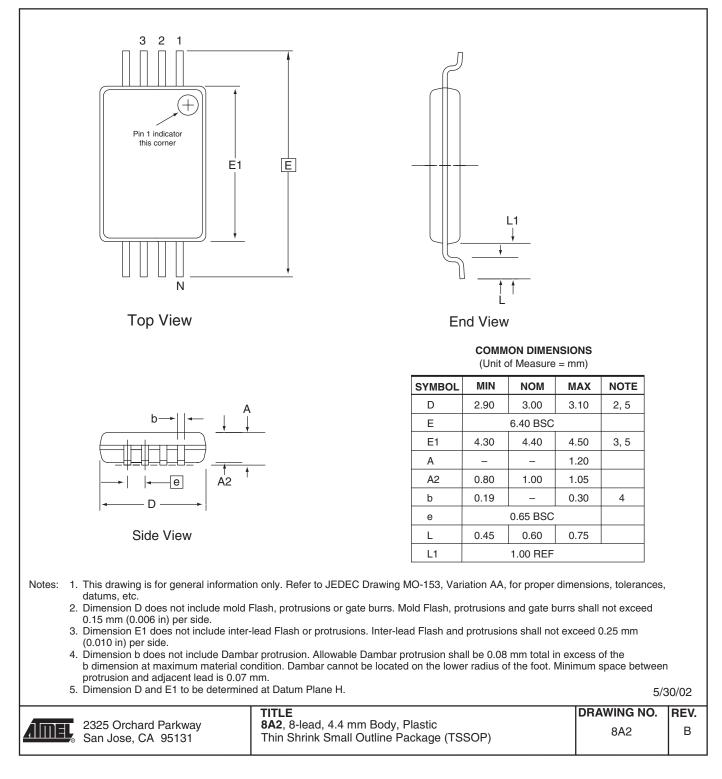


#### 8Y4 – SAP





#### 8A2 – TSSOP







### **Revision History**

Doc. Rev.	Comments
0670S	Implemented Revision History page; Added Note 1 "Not recommended for new design; please refer to AT24C256B datasheet" to AT24C256 part on Pages 1 and 14.





#### **Atmel Corporation**

2325 Orchard Parkway San Jose, CA 95131, USA Tel: 1(408) 441-0311 Fax: 1(408) 487-2600

#### **Regional Headquarters**

#### Europe

Atmel Sarl Route des Arsenaux 41 Case Postale 80 CH-1705 Fribourg Switzerland Tel: (41) 26-426-5555 Fax: (41) 26-426-5500

#### Asia

Room 1219 Chinachem Golden Plaza 77 Mody Road Tsimshatsui East Kowloon Hong Kong Tel: (852) 2721-9778 Fax: (852) 2722-1369

#### Japan

9F, Tonetsu Shinkawa Bldg. 1-24-8 Shinkawa Chuo-ku, Tokyo 104-0033 Japan Tel: (81) 3-3523-3551 Fax: (81) 3-3523-7581

#### **Atmel Operations**

*Memory* 2325 Orchard Parkway San Jose, CA 95131, USA Tel: 1(408) 441-0311 Fax: 1(408) 436-4314

#### Microcontrollers

2325 Orchard Parkway San Jose, CA 95131, USA Tel: 1(408) 441-0311 Fax: 1(408) 436-4314

La Chantrerie BP 70602 44306 Nantes Cedex 3, France Tel: (33) 2-40-18-18-18 Fax: (33) 2-40-18-19-60

#### ASIC/ASSP/Smart Cards

Zone Industrielle 13106 Rousset Cedex, France Tel: (33) 4-42-53-60-00 Fax: (33) 4-42-53-60-01

1150 East Cheyenne Mtn. Blvd. Colorado Springs, CO 80906, USA Tel: 1(719) 576-3300 Fax: 1(719) 540-1759

Scottish Enterprise Technology Park Maxwell Building East Kilbride G75 0QR, Scotland Tel: (44) 1355-803-000 Fax: (44) 1355-242-743

#### **RF**/Automotive

Theresienstrasse 2 Postfach 3535 74025 Heilbronn, Germany Tel: (49) 71-31-67-0 Fax: (49) 71-31-67-2340

1150 East Cheyenne Mtn. Blvd. Colorado Springs, CO 80906, USA Tel: 1(719) 576-3300 Fax: 1(719) 540-1759

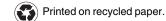
#### Biometrics/Imaging/Hi-Rel MPU/

High Speed Converters/RF Datacom Avenue de Rochepleine BP 123 38521 Saint-Egreve Cedex, France Tel: (33) 4-76-58-30-00 Fax: (33) 4-76-58-34-80

*Literature Requests* www.atmel.com/literature

Disclaimer: The information in this document is provided in connection with Atmel products. No license, express or implied, by estoppel or otherwise, to any intellectual property right is granted by this document or in connection with the sale of Atmel products. EXCEPT AS SET FORTH IN ATMEL'S TERMS AND CONDI-TIONS OF SALE LOCATED ON ATMEL'S WEB SITE, ATMEL ASSUMES NO LIABILITY WHATSOEVER AND DISCLAIMS ANY EXPRESS, IMPLIED OR STATUTORY WARRANTY RELATING TO ITS PRODUCTS INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTY OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT. IN NO EVENT SHALL ATMEL BE LIABLE FOR ANY DIRECT, INDIRECT, CONSEQUENTIAL, PUNITIVE, SPECIAL OR INCIDEN-TAL DAMAGES (INCLUDING, WITHOUT LIMITATION, DAMAGES FOR LOSS OF PROFITS, BUSINESS INTERRUPTION, OR LOSS OF INFORMATION) ARISING OUT OF THE USE OR INABILITY TO USE THIS DOCUMENT, EVEN IF ATMEL HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES. Atmel makes no representations or warranties with respect to the accuracy or completeness of the contents of this document and reserves the right to make changes to specifications and product descriptions at any time without notice. Atmel does not make any commitment to update the information contained herein. Unless specifications otherwise, Atmel products are not suitable for, and shall not be used in, automotive applications. Atmel's products are not intended, or warranted for use as components in applications intended to support or sustain life.

© 2006 Atmel Corporation. All rights reserved. Atmel<sup>®</sup>, logo and combinations thereof, Everywhere You Are<sup>®</sup> and others, are registered trademarks or trademarks of Atmel Corporation or its subsidiaries. Other terms and product names may be trademarks of others.



0670S-SEEPR-5/06